

Specifications in this document are tentative and subject to change.

# PS9307L,PS9307L2

R08DS0046EJ0001 Rev.0.01 Jan 25, 2012

0.6 A OUTPUT CURRENT, HIGH CMR, IGBT GATE DRIVE, 6-PIN SDIP PHOTOCOUPLER

#### DESCRIPTION

The PS9307L and PS9307L2 are optical coupled isolators containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

The PS9307L and PS9307L2 are in 6-pin plastic SDIP (Shrink Dual In-line Package). The PS9307L2 has 8 mm creepage distance. The mount area of 6-pin plastic SDIP is half size of 8-pin DIP.

The PS9307L and PS9307L2 are designed specifically for high common mode transient immunity (CMR) and high switching speed. It is suitable for driving IGBTs and MOS FETs.

The PS9307L is lead bending type (Gull-wing) for surface mounting.

The PS9307L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

## **FEATURES**

- Long creepage distance (8 mm MIN.: PS9307L2)
- Half size of 8-pin DIP
- Peak output current (0.6 A MAX., 0.4 A MIN.)
- High speed switching ( $t_{PLH}$ ,  $t_{PHL} = 175$  ns MAX.)
- High common mode transient immunity (CM<sub>H</sub>, CM<sub>L</sub> =  $\pm 50 \text{ kV/}\mu\text{s MIN}$ .)
- Operating Ambient Temperature (125 °C)
- Embossed tape product: PS9307L-E3, PS9307L2-E3: 2 000 pcs/reel
- Pb-Free product
- Safety standards
  - UL approved: No. E72422
  - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
  - SEMKO approved: No. 1115598
  - DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40024069 (Option)

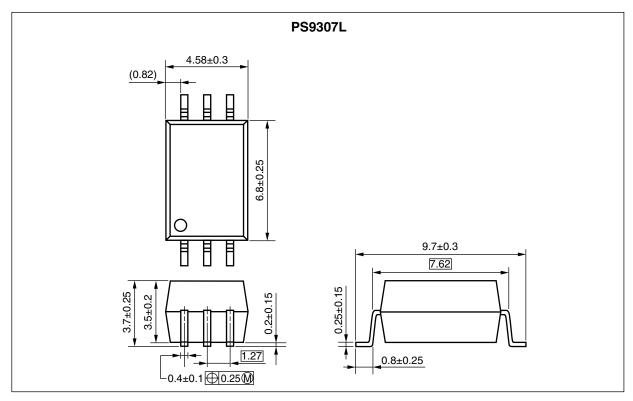
# PIN CONNECTION (Top View) 6 5 4 1. Anode 2. NC 3. Cathode 4. Vee 5. Vo 6. Vcc

## **APPLICATIONS**

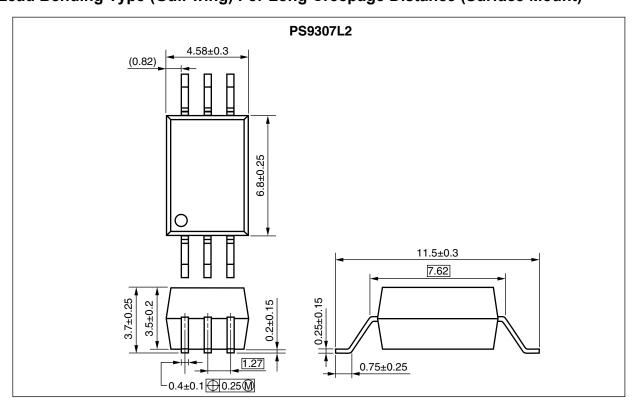
- IGBT, Power MOS FET Gate Driver
- Industrial inverter
- AC Servo
- PDP

## PACKAGE DIMENSIONS (UNIT: mm)

# Lead Bending Type (Gull-wing) For Surface Mount



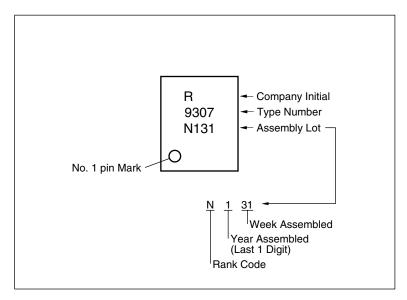
## Lead Bending Type (Gull-wing) For Long Creepage Distance (Surface Mount)



## PHOTOCOUPLER CONSTRUCTION

Parameter	PS9307L	PS9307L2
Air Distance (MIN.)	7 mm	8 mm
Outer Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

## **MARKING EXAMPLE**



## **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9307L	PS9307L-AX	Pb-Free	20 pcs (Tape 20 pcs cut)	Standard	PS9307L
PS9307L-E3	PS9307L-E3-AX	(Ni/Pd/Au)	Embossed Tape 2 000	products	
			pcs/reel	(UL, CSA,	
PS9307L2	PS9307L2-AX		20 pcs (Tape 20 pcs cut)	SEMKO	PS9307L2
PS9307L2-E3	PS9307L2-E3-AX		Embossed Tape 2 000	approved)	
			pcs/reel		
PS9307L-V	PS9307L-V-AX		20 pcs (Tape 20 pcs cut)	DIN EN60747-5-2	PS9307L
PS9307L-V-E3	PS9307L-V-E3-AX		Embossed Tape 2 000	(VDE0884 Part2)	
			pcs/reel	approved	
PS9307L2-V	PS9307L2-V-AX		20 pcs (Tape 20 pcs cut)	(Option)	PS9307L2
PS9307L2-V-E3	PS9307L2-V-E3-AX		Embossed Tape 2 000		
			pcs/reel		

Note: \*1. For the application of the Safety Standard, following part number should be used.

# ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current	I <sub>F</sub>	25	mA
	Peak Transient Forward Current (Pulse Width < 1 μs)	I <sub>F (TRAN)</sub>	1.0	Α
	Reverse Voltage	$V_R$	5	V
	Power Dissipation *1	P <sub>D</sub>	45	mW
Detector	High Level Peak Output Current *2	I <sub>OH (PEAK)</sub>	0.6	Α
	Low Level Peak Output Current *2	I <sub>OL (PEAK)</sub>	0.6	Α
	Supply Voltage	(V <sub>CC</sub> – V <sub>EE</sub> )	0 to 35	V
	Output Voltage		0 to V <sub>CC</sub>	V
	Power Dissipation *3	Pc	250	mW
Isolation Voltage *4		BV	5 000	Vr.m.s.
Operating Frequency		f	250	kHz
Operating Ambient Temperature		T <sub>A</sub>	-40 to +125	°C
Storage Temperature		T <sub>stg</sub>	–55 to +150	°C

Notes: \*1. Reduced to 1.2 mW/ $^{\circ}$ C at  $T_A$  = 110 $^{\circ}$ C or more.

- \*2. Maximum pulse width = 10  $\mu$ s, Maximum duty cycle = 0.5%
- \*3. Reduced to 3.9 mW/ $^{\circ}$ C at T<sub>A</sub> = 85 $^{\circ}$ C or more.
- \*4. AC voltage for 1 minute at  $T_A$  = 25°C, RH = 60% between input and output. Pins 1-3 shorted together, 4-6 shorted together.

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	$(V_{CC} - V_{EE})$	10		30	V
Forward Current (ON)	I <sub>F (ON)</sub>	8		12	mA
Forward Voltage (OFF)	V <sub>F (OFF)</sub>	-2		0.8	V
Operating Ambient Temperature	T <sub>A</sub>	-40		125	°C

# ELECTRICAL CHARACTERISTICS (at RECOMMENDED OPERATING CONDITIONS, $V_{\text{EE}}$ = GND, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10 mA, T <sub>A</sub> = 25°C	1.3	1.56	1.8	V
	Reverse Current	$I_R$	V <sub>R</sub> = 3 V, T <sub>A</sub> = 25°C			10	μΑ
	Input Capacitance	C <sub>IN</sub>	$f = 1 \text{ MHz}, V_F = 0 \text{ V}$		30		pF
Detector	High Level Output Current	I <sub>OH</sub>	$V_{\rm O} = (V_{\rm CC} - 4 \text{ V})^{*2}$	0.2			Α
			$V_{\rm O} = (V_{\rm CC} - 10 \text{ V})^{*3}$	0.4	0.7		
	Low Level Output Current	I <sub>OL</sub>	$V_{O} = (V_{EE} + 2.5 \text{ V})^{*2}$	0.2			Α
			$V_{O} = (V_{EE} + 10 \text{ V})^{*3}$	0.4	0.7		
	High Level Output Voltage	V <sub>OH</sub>	I <sub>F</sub> = 10 mA, I <sub>O</sub> = 100 mA *4	V <sub>CC</sub> - 3.0	V <sub>CC</sub> – 1.7		V
	Low Level Output Voltage	$V_{OL}$	$I_F = 0 \text{ mA}, I_O = 100 \text{ mA}$		0.4	1.0	V
	High Level Supply Current	I <sub>CCH</sub>	$I_F = 10 \text{ mA}, I_O = 0 \text{ mA}$		1.2	2.0	mA
	Low Level Supply Current	I <sub>CCL</sub>	$I_F = 0 \text{ mA}, I_O = 0 \text{ mA}$		1.3	2.0	mA
Coupled	Threshold Input Current	I <sub>FLH</sub>	$I_0 = 0 \text{ mA}, V_0 > 5 \text{ V}$		2.1	5.0	mA
	$(L \rightarrow H)$						
	Threshold Input Voltage	$V_{FHL}$	$I_{O} = 0 \text{ mA}, V_{O} < 5 \text{ V}$	8.0			V
	$(H \rightarrow L)$						

Notes: \*1. Typical values at  $T_A$  = 25°C,  $V_{CC} - V_{EE}$  = 30 V.

- \*2. Maximum pulse width = 50  $\mu$ s, Maximum duty cycle = 0.2%.
- \*3. Maximum pulse width = 10  $\mu$ s, Maximum duty cycle = 0.5%.

# SWITCHING CHARACTERISTICS (at RECOMMENDED OPERATING CONDITIONS, $V_{EE}$ = GND, unless otherwise specified)

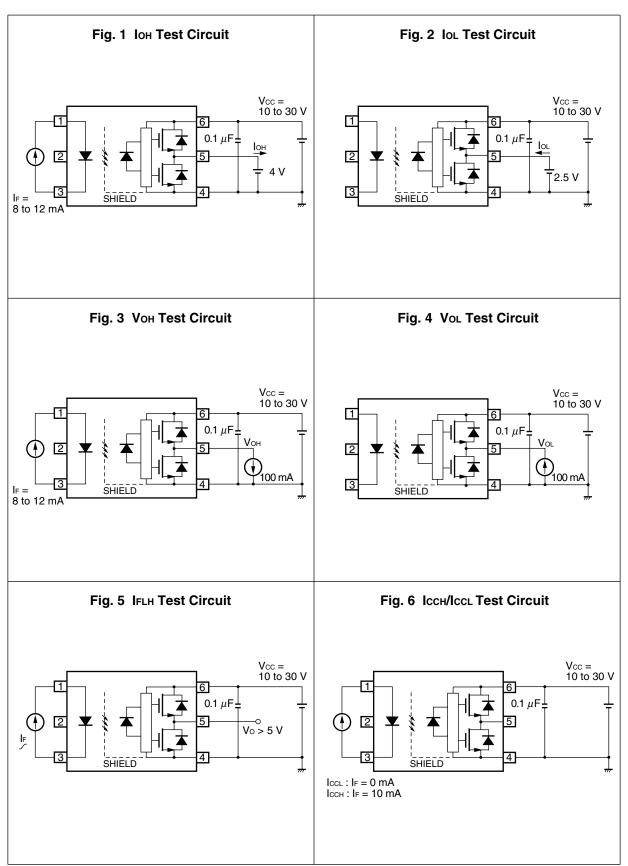
Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Propagation Delay Time $(L \rightarrow H)$	t <sub>PLH</sub>	$R_g = 47 \Omega, C_g = 3 nF,$	40	75	175	ns
Propagation Delay Time $(H \rightarrow L)$	t <sub>PHL</sub>	f = 50 kHz,	40	90	175	ns
Pulse Width Distortion (PWD)	t <sub>PHL</sub> -t <sub>PLH</sub>	Duty Cycle = 50% <sup>*2</sup> ,			90	ns
Propagation Delay Time	t <sub>PHL</sub> -t <sub>PLH</sub>	$I_F = 10 \text{ mA}, V_{CC} = 30 \text{ V}$	-120		120	ns
(Difference Between Any Two						
Products)						
Rise Time	t <sub>r</sub>			30		ns
Fall Time	t <sub>f</sub>			30		ns
Common Mode Transient	CM <sub>H</sub>	$T_A = 25^{\circ}C$ , $I_F = 10$ mA,	50			kV/ <i>μ</i> s
Immunity at High Level Output		$V_{CC} = 30 \text{ V}, V_{CM} = 1.5 \text{ kV}$				
Common Mode Transient	CM <sub>L</sub>	$T_A = 25^{\circ}C$ , $I_F = 0$ mA,	50			kV/ <i>μ</i> s
Immunity at Low Level Output		$V_{CC} = 30 \text{ V}, V_{CM} = 1.5 \text{ kV}$				

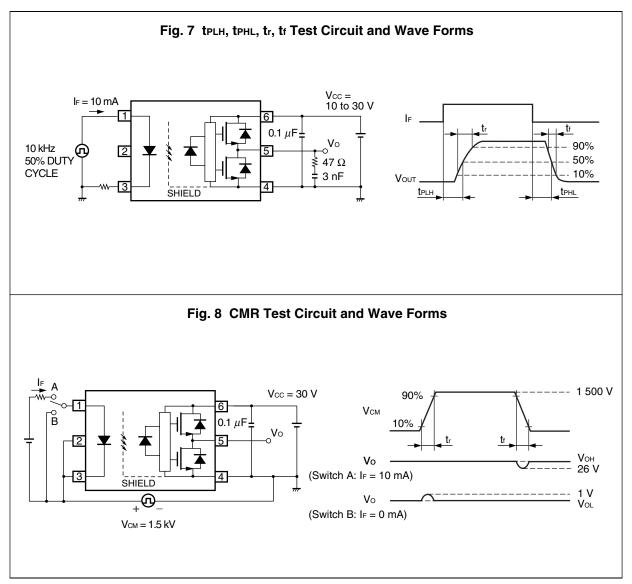
Notes: \*1. Typical values at  $T_A = 25^{\circ}C$ ,  $V_{CC}-V_{EE} = 30 \text{ V}$ .

<sup>\*4.</sup> V<sub>OH</sub> is measured with the DC load current in this testing.

<sup>\*2.</sup> This load condition is equivalent to the IGBT load at 1 200 V/25 A.

## **TEST CIRCUIT**

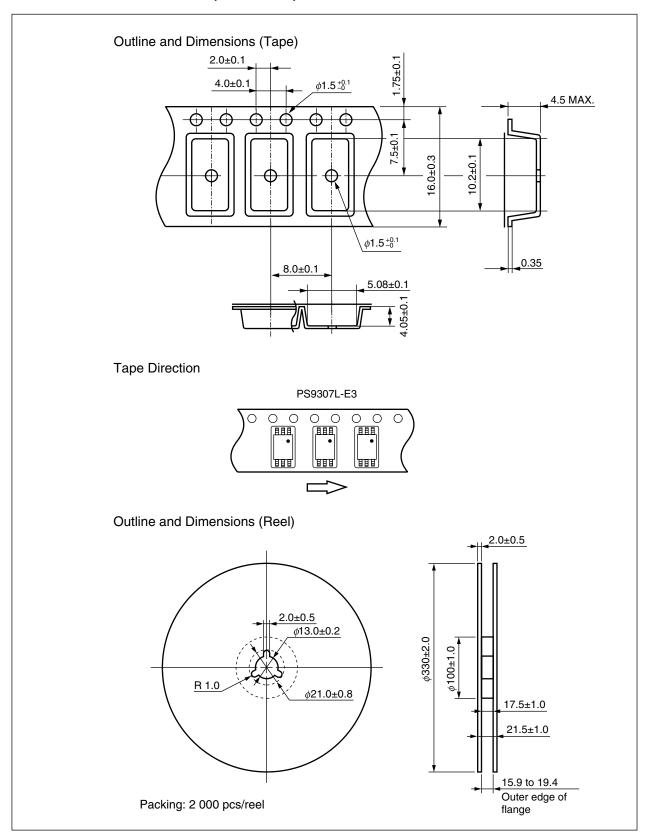


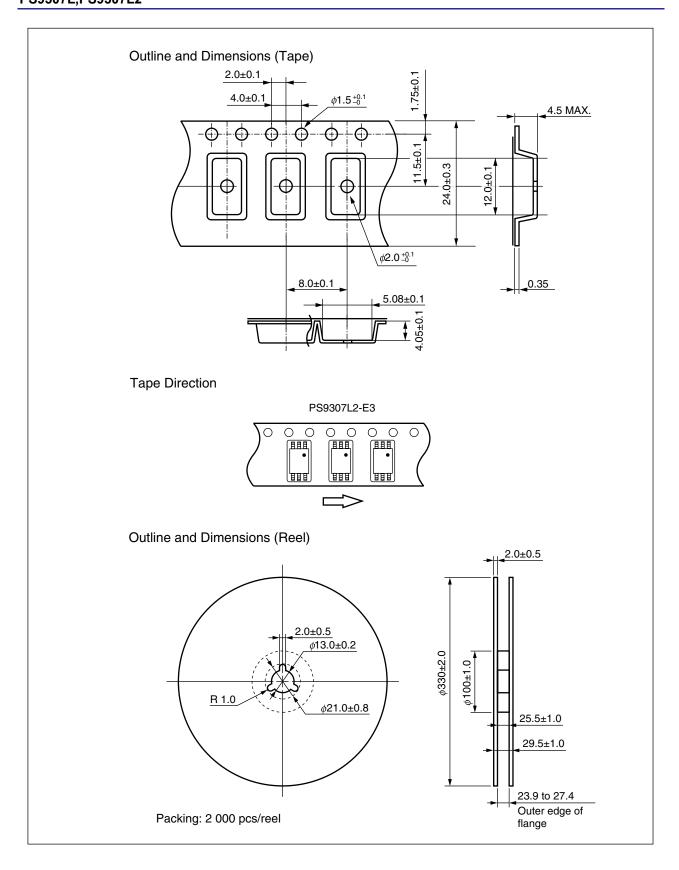


**Remarks 1.** Common Mode Transient Immunity at High Level Output is the maximum value of  $dV_{CM}/dt$  at which the output remains High Level (e.g.  $V_O > 15 \text{ V}$ ).

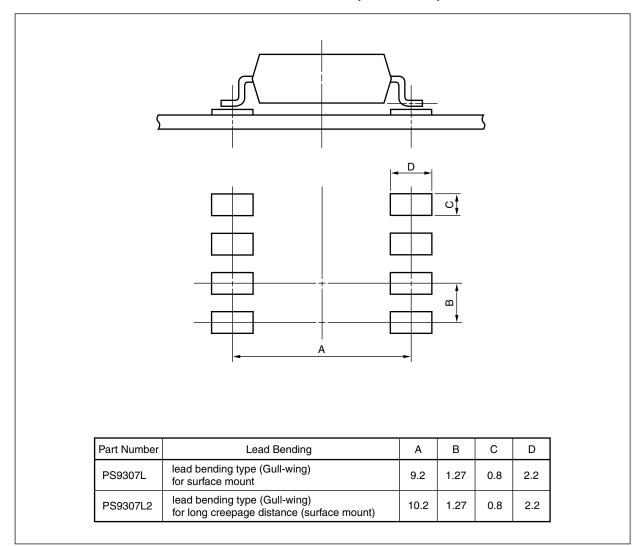
2. Common Mode Transient Immunity at Low Level Output is the maximum value of  $dV_{CM}/dt$  at which the output remains Low Level (e.g.  $V_O < 1.0 \text{ V}$ ).

## TAPING SPECIFICATIONS (UNIT: mm)





# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



## NOTES ON HANDLING (UNIT: mm)

### CAUTIONS REGARDING NOISE

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

#### **USAGE CAUTIONS**

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. Board designing
  - (1) By-pass capacitor of more than 0.1  $\mu$ F is used between V<sub>CC</sub> and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
  - (2) When designing the printed wiring board, ensure that the pattern of the IGBT collectors/emitters is not too close to the input block pattern of the photocoupler.

    If the pattern is too close to the input block and coupling occurs, a sudden fluctuation in the voltage on the IGBT output side might affect the photocoupler's LED input, leading to malfunction or degradation of characteristics.
    - output side might affect the photocoupler's LED input, leading to malfunction or degradation of characteristics. (If the pattern needs to be close to the input block, to prevent the LED from lighting during the off state due to the abovementioned coupling, design the input-side circuit so that the bias of the LED is reversed, within the range of the recommended operating conditions, and be sure to thoroughly evaluate operation.)
  - (3) Pin 2 (which is an NC\*1 pin) can either be connected directly to the GND pin on the LED side or left open. Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.

Note: \*1. NC: Non-Connection (No Connection).

- 3. Make sure the rise/fall time of the forward current is 0.5  $\mu$ s or less.
- 4. In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is 3  $V/\mu$ s or less.
- 5. Avoid storage at a high temperature and high humidity.



## Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

**Revision History** 

## PS9307L,PS9307L2 Preliminary Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	Jan 25, 2012	_	First edition issued	

#### Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- 2. Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc
  - Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools personal electronic equipment; and industrial robots.
  - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
  - Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical "Specific": implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics



#### SALES OFFICES

## Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information

enesas Electronics America Inc. 80 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. dl: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited Dukes Meadow, Millboard Road, Boume End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-2035-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No. 1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-5887-7589

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852-2886-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiv Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 1 harbourFront Avenue, #06-10, keppel Bay Tower, Singapore 098632 Tel: +65-6213-0200, Fax: +65-6278-8001

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd. 11F., Samik Lavied' or Bidg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea Tel: 482-2-558-3737, Fax: 482-2-558-5141

© 2012 Renesas Electronics Corporation. All rights reserved.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Renesas Electronics:

PS9307L2-AX PS9307L-V-E3-AX PS9307L-AX